

## Product Overview

### FGH75T65SHDTL4: IGBT, 650 V, 75 A Field Stop Trench

For complete documentation, see the data sheet.

Using novel field stop IGBT technology, Fairchild's new series of field stop 3<sup>rd</sup> generation IGBTs offer the optimum performance for solar inverter, UPS, welder, telecom, ESS and PFC applications where low conduction and switching losses are essential.

### Features

- Maximum Junction Temperature:  $T_J = 175^\circ\text{C}$
- Positive Temperature Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage:  $V_{CE(sat)} = 1.6\text{ V(Typ.) @ } I_C = 75\text{ A}$
- 100% of the Parts Tested for  $I_{LM}(1)$
- High Input Impedance
- Fast Switching
- Tighten Parameter Distribution
- RoHS Compliant

### Part Electrical Specifications

Product	Compliance	Status	$V_{ES}^{(BR)C}$ Typ (V)	$I_C$ Max (A)	$V_{GE(sat)}$ Typ (V)	$V_F$ Typ (V)	$E_{off}$ Typ (mJ)	$E_{on}$ Typ (mJ)	$T_{rr}$ Typ (ns)	$I_{rr}$ Typ (A)	Gate Charge Typ (nC)	Short Circuit Withstand ( $\mu\text{s}$ )	$E_{AS}$ Typ (mJ)	$P_D$ Max (W)	Co-Pack aged Diode	Package Type
FGH75T65SHDTL4	Pb-free Halide free	Active	650	75	1.6	1.8	1.56	1.06	76	-	126	-	-	455	Yes	TO-247-4

For more information please contact your local sales support at [www.onsemi.com](http://www.onsemi.com).

Created on: 11/26/2018